8-bit Proprietary Microcontrollers

CMOS

F²MC-8L MB89210 Series

MB89215/F217/P215/PV210

DESCRIPTION

The MB89210 series is a one-chip microcontroller that features a compact instruction set and contains a range of peripheral functions including timers, a serial interface, A/D converters and external interrupts.

■ FEATURES

- F²MC-8L CPU core
- Maximum memory spaces : 64 Kbytes
- Minimum instruction execution time : 0.32 μs to 5.12 μs (at 12.5 MHz)
- Interrupt processing time : 2.88 µs to 46.08 µs (at 12.5 MHz)
- I/O port
- : Max 22
- 21-bit time base timer
- 8-bit PWM timer
- 8-/16-bit capture timer/counter : 2 ch
- Watchdog timer
- 12-bit PPG timer

PACKAGE

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- 10-bit A/D converter : 8 ch
- LIN-UART
- 8-bit serial I/O
- External Interrupt : 3 ch
- External or CR (built-in) oscillation clock, switchable
- Low power consumption modes (stop modes, sleep modes)
- Package : SSOP-30,QFP-48, MQFP-48
- CMOS technology

■ PRODUCT LINEUP

	Part number	MB89215	MB89F217	MB89P215	MB89PV210				
Parameter									
Туре	9	For mass products (Mask ROM product)	Flash products (Flash ROM product)	One-time product (for small-scale production)	Piggy back/ Evaluation product (for development)				
RON	1 capacity	16 Kbyte (Built-in ROM)	32 Kbyte (Built-in Flash memory)	16 Kbyte (Built-in PROM)	32 Kbyte (External EPROM)				
RAM	1 capacity	512 byte	1 Kbyte	512 byte	2 Kbyte				
CPU	functions	Number of basic instructions: 136Instruction bit length: 8 bitsInstruction length: 1 to 3 bytesData bit length: 1, 8, and 16 bitsMinimum instruction execution time: 0.32 µs to 5.12 µs (at 12.5 MHz)Interruption processing time: 2.88 µs to 46.08 µs (at 12.5 MHz)							
	Ports	General purpose I/O \times 1	port $ imes$ 21 (also usable	as resources) Genera	al purpose input port				
	21-bit time base timer	21 bits Interrupt cycle : at 10 MHz (0.82 ms,3.3 ms,26.2 ms,419.4 ms)							
	Watchdog timer	Reset generation cycle : at 10 MHz (Min 419.4 ms)							
	8-bit PWM timer	8-bit interval timer operation (supports square wave output, operating clock period : $0.4 \ \mu s$ to 25.6 μs) 8-bit resolution PWM operation (conversion period : 102.4 μs to 26.84 μs)							
Peripheral functions	8/16-bit capture timer counter	8-bit capture timer/counter \times 1 channel + 8-bit timer or 16-bit capture timer/counter \times 1 channel Capable of event count operation and square wave output using external clock input with 8-bit timer 0 or 16-bit counter							
eripheral	LIN-UART	Full duplex, Synchronous/asynchronous transfer (with start/stop bit), Capable of setting over 30,000 different baud rates using a 15-bit reload counter Support for the LIN protocol, slave nodes, and LIN synch break/sync field detection							
Å.	8-bit serial I/O	8-bit length, Selectable LSB first or MSB first Transfer clock (0.8 μs external, 0.8 μs, 3.2 μs, 12.8 μs internal)							
	12-bit PPG timer	Output requency : Selectable pulth width and cycle (Cycle : 1.6 μ s to 419.3 ms)							
External interrupt circuit3-channel (interrupt vector, request flag, requesr output acceptant Edge selectable (selectable rising, falling or both edge) Can be use for recovery from stop or sleep mode (edge detection stop mode).									
	A/D converter		ion (conversion time	annel n (conversion time : 15.2 μs/10 MHz) by an 8-/16-bit timer/counter output or time base timer output					
Stan	dby mode		Sleep mode a	nd Stop mode					
Ope	rating voltage *	3.5 V to 5.5 V	3.5 V to 5.5 V	3.5 V to 5.5 V	3.5 V to 5.5 V				
CR(I	ouilt-in) oscillator	Yes	Yes	Yes	No				

*: The minimum operating voltage varies with the operating frequency, the function and the connected ICE.

Note : Unless otherwise stated, clock periods and conversion times are for 10 MHz operation with the internal clock operating at maximum speed.

PACKAGES AND CORRESPONDING PRODUCTS

Package	MB89215	MB89F217	MB89P215	MB89PV210
FPT-30P-M02	0	×	0	X *1
FPT-48P-M13	0	0	×	X *2
MQP-48C-P02	×	×	×	0
Power supply pins	Vcc,Vss \times 2	Vcc, Vss × 3, AVcc, AVss	Vcc,Vss×2	Vcc, Vss × 2, AVcc, AVss

O:Yes \times :No

*1 : Adapter for 48-pin to 30-pin conversion (manufactured by Sunhayato Corp.) Part number : 48QF-30SOP-8L Inquiry : Sunhayato Corp. TEL : (81)-3-3984-7791 FAX : (81)-3-3971-0535 E-mail : adapter@sunhayato.co.jp
*2 : Adapter for 48 pin (E)(A) to 48 pin (MASK/ELASH) conversion

*2 : Adapter for 48-pin (EVA) to 48-pin (MASK/FLASH) conversion. Part number : 48QF2-48QF2-8L-FJ Inquiry : Sunhayato Corp. TEL : (81)-3-3984-7791 FAX : (81)-3-3971-0535 E-mail : adapter@sunhayato.co.jp

DIFFERENCES AMONG PRODUCTS

1. Memory space

When this product is used in a piggy-back or other evaluation configuration, it is necessary to carefully confirm the differences between the model being used and the product it is evaluating.

2. Current Consumption

- On the MB89PV210, the additional current consumed by the EPROM is added at the connecting socket on the back side.
- When operating at low speed, the current consumption in the one-time PROM or EPROM models is greater than on the mask ROM models. However, current consumption in sleep or stop modes is identical. However, in sleep/stop mode the current consumption is the same.



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N.C. : Internal connection only. Not for use.

■ PIN DESCRIPTIONS

	Pin no.		. .	Circuit	
SSOP*1	QFP*2	MQFP*3	Pin name	type	Function
10	10	4	X0	A	Connecting pins to crystal oscillator or other oscillator.
9	9	5	X1		When using ecternal clock, input to X0 and X1 is left open.
—	37	_	MOD0	C/D1*4	Input pins for memory access mode setting. Connect directly to Vss.
_	38		MOD1	0/01	Input pins for memory access mode setting. Connect directly to Vss.
5	1	2	MODA	C/D ₂ *5	Input pins for memory access mode setting. Connect directly to Vss.
6	2	3	RST	E	Reset I/O pin. This pin has pull-up resistance with N-ch open drain or hyster- esis input. At an internal reset request, an "L" signal is output. An "L" level input initializes the internal circuits.
27 to 30	36, 39 to 41	25 to 28	P00/AN4 to P03/AN7	G	General purpose I/O port. Hysteresis input. These pins also functions as the analog input of A/D converter.
1 to 3	44 to 46	46 to 48	P04/INT0 to P06/INT2		General purpose I/O port. These pins also functions as the external interrupt input. Hysteresis input.
4	47	1	P07/EC0		General purpose I/O port. This pin also functions as external clock of 8-/16-bit capture timer/counter 0 or capture input pin. Hysteresis input.
13	16	10	P10/SCK		General purpose I/O port. This pin also functions as clock input/output pin of serial I/O. Hysteresis input.
14	17	11	P11/SO		General purpose I/O port. This pin also functions as the data output pin of serial I/O. Hysteresis input.
15	18	12	P12/SI	F	General purpose I/O port. This pin also functions as the data input pin of serial I/O. Hysteresis input.
16	20	13	P13/TO0		General purpose I/O port. This pin also functions as the output pin of 8-/16-bit capture timer/counter 0. Hysteresis input.
17	21	14	P14/UCK/ EC1		General purpose I/O port. This pin also functions as the clock input/output pin of LIN- UART and the external clock of 8-/16-bit capture timer/counter 1 or capture input pin. Hysteresis input.
18	22	15	P15/UO		General purpose I/O port. This pin also functions as the data output pin of LIN-UART. Hysteresis input

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	Pin no.		Pin name	Circuit	Function		
SSOP*1	QFP*2	MQFP*3	Pin name	type	T unction		
19	23	16	P16/UI	Н	General purpose I/O port. This pin also functions as the data input pin of LIN-UART. General port input is hysteresis and resource input is CMOS.		
20	25	17	P17/PPG	F	General purpose I/O port. F This pin also functions as 12-bit PPG timer output. Hysteresis input.		
23 to 26	32 to 35	21 to 24	P20/AN0 to P23/AN3	G	General purpose I/O port. Shared for A/D converter analog input pin. Hysteresis input.		
11	11	8	P30/PWM/ TO1	F	General purpose I/O port. This pin also functions as the output pin of 8-bit PWM and 8-/ 16-bit capture timer/counter 1. Hysteresis input.		
12	15	9	P31	В	General purpose I/O port of CMOS type.		
21	42	7	Vcc		Power supply pin.		
8,22	8, 19, 43	6,43	Vss		Power supply pin (GND). Use the both pins at the same voltage level.		
_	27	20	AVcc		A/D converter power supply pin. Apply potential under Vcc to this pin.		
_	28	19	AVss		A/D converter power supply pin (GND). Use at the same voltage level as the Vss supply.		
7	7		С		This is the power supply stabilization capacitor pin for MB89F217 and MB89P215. Connect an external capacitor of 0.1 μ F. MB89215 is not internally connected. It is unnecessary to connect a capacitor.		
	3 to 6, 12 to 14, 24, 26, 29 to 31, 48	18, 29 to 42, 44,45	N.C.		Internal connect pin. Be sure this pin is left open.		

*1 : FPT-30P-M02

*2 : FPT-48P-M13

*3 : MQP-48C-P02

*4 : MB89F217 is C.

*5 : MB89F217 and MB89P215 are C.

■ EXTERNAL EPROM PIN DESCRIPTION (MB89PV210 only)

Pin no.	Pin name	I/O	Function
49	Vpp	0	"H" level output pin.
50 51 52 53 54 55 58 59 60	A12 A7 A6 A5 A4 A3 A2 A1 A0	0	Address output pin.
61 62 63	01 02 03	I	Data input pin.
64	Vss	0	Power supply pin (GND).
65 66 67 68 69	O4 O5 O6 O7 O8	I	Data input pin.
70	CE	0	Chip acceptance pin for ROM. Output "H" at standby.
71	A10	0	Address output pin.
73	OE	0	Output acceptance pin for ROM. Output "L" usually.
75 76 77 78 79	A11 A9 A8 A13 A14	0	Address output pin.
80	Vcc	0	Power supply pin for EPROM.
56 57 72 74	N.C.		Internal connect pin. Must be left open.

■ I/O CIRCUIT TYPE



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■ HANDLING DEVICES

1. Preventing Latchup

Latchup may occur on CMOS ICs if voltage higher than Vcc or lower than Vss is applied to input or output pins other than the medium-and high-voltage pins or if voltage higher than the rating is applied between Vcc and Vss.

When latchup occurs, power supply current increases rapidly and might thermally damage elements. When using, take great care not to exceed the absolute maximum ratings.

Also, take care to prevent the analog input from exceeding the digital power supply (V_{CC}) when the analog system power supply is turned on and off.

To supply power, turn on the digital power supply (Vcc) and then the analog power supply (AVcc).

2. Treatment of Unused Input Pins

Leaving unused input teminals open may lead to permanent damage due to malfunction and latchup; pull up or pull down the terminals through the resistors of 2 k Ω or more.

Make the unused I/O terminal in a state of output and leave it open and if it is in an input state, handle it with the same procedure as the input terminals.

3. Treatment of N.C. Pins

Any pins marked "NC" (not connected) must be left open.

4. Power Supply Voltage Fluctuations

Although Vcc power supply voltage is assured to operate within the rated range, a rapid fluctuation of the voltage could cause malfunctions even if it occurs within the rated range. Stabilizing voltage supplied to the IC is therefore important. As stabilization guidelines, it is recommended to control power so that V_{CC} ripple fluctuations (P-P value) will be less than 10% of the standard V_{CC} value at the commercial frequency (50 to 60 Hz) and the transient fluctuation rate will be less than 0.1 V/ms.

5. Treatment of power supply pin

All Vss power suppluy pin must be use at the same voltage level.

Connect to be AVcc = Vcc, AVss = Vss even if the A/D converters are not in use in MB89PV210.

6. Notes on Using External Clock

When an external clock is used, oscillation stabilization time is required for even power-on reset and release from stop mode.

7. Notes on using the CR (internal) oscillator

To use the CR (internal) oscillator as the operating clock for the MB89215, MB89F217 or MB89P215, adjust the timer value and baud rate setting.

8. Program Execution in RAM

When the MB89PV210 is used with an emulation pod other than the MB2144-508, no program can be executed in RAM.

9. Operation check for evaluating the LIN-UART

When the MB89215, MB89F217 or MB89P215 uses the CR (internal) oscillator as the clock for the LIN-UART, the evaluation program (MB89PV210 [customized for external oscillation]) requires an operation check within a range of oscillation frequencies from 8.5 MHz to 11.5 MHz.

10. Handling reset pin

Reset pin must be inputted external reset.

11. Up/down conversion circuit stabilization waiting time

MB89210 series contains the following products and the operating characteristics vary with whether they contain the internal stepdown circuit.

Product name	Operating voltage *	Down conversion
MB89215	3.5 V to 5.5 V	not built-in
MB89F217	3.5 V to 5.5 V	built-in
MB89P215	3.5 V to 5.5 V	built-in
MB89PV210	3.5 V to 5.5 V	not built-in

* : The minimum operating voltage varies with the operating frequency, the function and the connected ICE.

The same built-in resources are used for the above product types; operating sequences after the power-on reset are different depending on whether they have the internal voltages step-down circuit.

The operating sequences after the power-on reset with the different models will be described below.



As described above, CPU starts at delayed time with the product having the internal voltage step-down circuit compared with the product not having the internal voltage step-down circuit. This is because the time should be allowed for the stabilization time for voltage step-down circuit for normal operation.

Note : As the period of the oscillation is unstable immediately after oscillation starts, the listed oscillation stabilization delay times are guides only.

12. Treatment of analog input

The analog input also serves as a general-purpose input/output port. The A/D enable register is initialized at a reset. When the intermediate-level signal is input in port input mode (ADEN:ADEx = 0), an input leakage current flows to the gate. Set the corresponding pin to an analog input.

■ PROGRAMMING AND ERASING FLASH MEMORY ON THE MB89F217

1. Flash Memory

The flash memory is located between 8000_H and FFFF_H in the CPU memory map and incorporates a flash memory interface circuit that allows read access and program access from the CPU to be performed in the same way as mask ROM. Programming and erasing flash memory is also performed via the flash memory interface circuit by executing instructions in the CPU. This enables the flash memory to be updated in place under the control of the CPU, providing an efficient method of updating program and data.

2. Flash Memory Features

- 32 K byte × 8-bit configuration : (16 K + 8 K + 8 K sectors)
- Automatic programming algorithm (Embedded algorithm* : Equivalent to MBM29LV200)
- Includes an erase pause and restart function
- Data polling and toggle bit for detection of program/erase completion
- Detection of program/erase completion via CPU interrupt
- Compatible with JEDEC-standard commands
- Sector Erasing (sectors can be combined in any combination)
- No. of program/erase cycles : 10,000 (Min)
- * : Embedded Algorithm is a trademark of Advanced Micro Devices.

3. Procedure for Programming and Erasing Flash Memory

Programming and reading flash memory cannot be performed at the same time. Accordingly, to program or erase flash memory, the program must first be copied from flash memory to RAM so that programming can be performed without program access from flash memory.

4. Flash Memory Register

• Control status register (FMCS)

	bit7	bit6	bit5	bit4	bit3	bit2	bit1	bit0	
Address 007Aн	INTE	RDYINT	WE	RDY	Reserved	Reserved	_	Reserved	Initial value 0 0 0 X 0 0 - 0в
	R/W	R/W	R/W	R	R/W	R/W	_	R/W	

5. Sector Configuration

The table below shows the sector configuration of flash memory and lists the address of each sector for both during CPU access a flash memory programming.

• Sector configuration of flash memory

FLASH Memory	CPU Address	Programming Address*
16 K bytes	FFFF _H to C000 _H	1FFFFн to 1C000н
8 K bytes	BFFF _H to A000 _H	1BFFFн to 1A000н
8 K bytes	9FFFн to 8000н	19FFFн to 18000н

* : The programmer address is the address to be used instead of the CPU address when programming data from a parallel flash memory programmer. Use the programmer address on programming or erasing using a generalpurpose parallel programmer.

6. ROM Writer Adapters and Recommended ROM Writers

Part	Package	Applicable adapter model	Recommended writer		
number	name	Sunhayato Corp.	Ando Electric Co., Ltd.	MINATO ELECTRONICS INC.	
MB89F217PFM	FPT-48P-M13	FLASH-48QF2-32DP-8LF	AF9708*1 AF9709/09B*1	MODEL-1890A ^{*2} Ver2.8 or more	

*1 : For the writer version and type code, please check the device list in homepage of the Flash Support Group, Inc as follow ; http://www.j-fsg.co.jp/

*2 : In addition to this adaptor, the conversion basis is required Conversion basis : H910-1148

Inquiries :	Sunhayato Corp.	FAX	: (81) -3-3984-7791 : (81) -3-3971-0535 : adapter@sunhayato.co.jp
	Flash Support Group, Inc	FAX	: (81) -53-428-8377
	MINATO ELECTRONICS INC.		: (81) -45-591-5611 : (81) -45-592-2854

■ PROGRAMMING TO OTPROM ON THE MB89P215

1. Memory space



2. Programming to the OTPROM

To program to the OTPROM using an EPROM programmer AF220/AF210/AF120/AF110 (manufacturer : Yokogawa Digital Computer Corp.).

Inquiry : Yokogawa Digital Computer Corp. : TEL(81)-42-333-6224

Note : Programming to the OTPROM with MB89P215 is serial programming mode only.

3. Programming Adaptor for OTPROM

To program to the OTPROM using an EPROM programmer AF220/AF210/AF120/AF110, use the programming adapter (manufacturer : Sunhayato Corp.) listed below.

Adaptor socket : ROM3-FPT30M02-8L3

Inquiry : Sunhayato Corp. : TEL : (81)-3-3984-7791 FAX : (81)-3-3971-0535

E-mail : adapter@sunhayato.co.jp

4. Programming yields

All bits cannot be programmed at Fujitsu shipping test to a blanked OTPROM microcomputer, due to its nature. For this reason, a programming yield of 100% cannot be assured at all times.

■ EPROM WRITING TO PIGGY-BACK/EVALUATION CHIPS

1. EPROM model

MBM27C256A-20TVM

2. Writer adapter

For writing to EPROM using a ROM writer, use one of the writer adapters shown below (manufactured by Sunhayato).

Package	Adapter socket model
LCC-32	ROM-32LC-28DP-S
Inquiries should be addressed to Sunha	ayato Corp. : TEL : (81)-3-3984-7791

FAX : (81)-3-3971-0535 E-mail : adapter@sunhayato.co.jp

3. Memory space

Shown below the memory space in each mode.



4. Writing to EPROM

- (1) Set up the EPROM writer for the MBM27C256A.
- (2) Load program data on to the EPROM programmer at 0000_H to 7FFF_H.
- (3) Program 0000 ${\rm H}$ to 7FFF ${\rm H}$ with the EPROM programmer.

BLOCK DIAGRAM



CPU CORE

1. Memory space

The MB89210 series has 64 KB of memory space, containing all I/O, data areas, and program areas. The I/O area is located at the lowest addresses, with the data area placed immediately above. The data area can be partitioned into register areas, stack areas, or direct access areas depending on the application. The program area is located at the opposite end of memory, closest to the highest addresses, and the highest part of this area is assigned to the tables of interrupt and reset vectors and vector call instructions. The following diagram shows the structure of memory space in the MB89210 series.



2. Register

The MB89210 series has two types of registers; the registers dedicated to specific purposes in the CPU and the general-purpose registers. The dedicated registers are as follows:

Program counter (PC)	: 16-bit length, shows the locations where instructions are stored.
Accumulator (A)	: 16-bit length, a temporary memory register for calculation operations. In the case of an 8-bit data processing instruction, the lower one byte is used.
Temporary accumulator (T)	: 16-bit length, performs calculations with the accumulator. In the case of an 8-bit data processing instruction, the lower one byte is used.
Index register (IX)	: 16-bit length, a register for index modification.
Extra pointer (EP)	: 16-bit length, apointer indicating memory addresses.
Stack pointer (SP)	: 16-bit length, indicates stack areas.
Program status (PS)	: 16-bit length, contains register pointer and condition code.



The PS register can further be divided into the register bank pointer in the higher 8 bits (RP) and the condition code register in the lower 8 bits (CCR). (See the diagram below.)



The RP points to the address of the register bank currently in use. The relationship between the pointer contents and the actual address is based on the conversion rule shown next.

Ile for Conversion of A	ctual	Addr	esse	s in t	he G	ienei	al-pi	urpo		0	er Are her b		C)P co	ode l	ower
	"0"	"0"	"0"	"0"	"0"	"0"	"0"	"1"	R4	R3	R2 I	٦1	R0 I	52	b1	b0
Generated address	*	*	*	*	*	•	*	•	*	*	*	•	*	•	*	*
Generated address	A15	A14	A13	A12	A11	A10	A9	A8	A/	A6	A5	A4	A3	A2	A1	A0

The CCR consists of the bits indicating arithmetic operation results or transfer data contents and the bits that control CPU operations at the time of an interrupt.

H flag : Set to 1 if calculations result in carry operations from bit 3 to bit 4 or borrow operations from bit 4 to bit 3, otherwise set to 0.

The flag is for decimal adjustment instructions; do not use for other than additions and subtractions.

- I flag : This flag is set to 1 if interrupts are enabled, and 0 if interrupts are prohibited. The default value at reset is 0.
- IL1, 0 : Indicates the level of the interrupt currently enabled. An interrupt is processed only if its level is higher than the value this bit indicates.

IL1	IL0	Interrupt level	High-low		
0	0	1	Higher		
0	1	I	†		
1	0	2	↓		
1	1	3	Lower = no interruption		

N flag : Set to 1 if the highest bit is 1 after a calculation, otherwise cleared to 0.

Z flag : Set to 1 if a calculation result is 0, otherwise cleared to 0.

V flag : Set to 1 if a 2's complement overflow results during a calculation, otherwise cleared to 0.

C flag : Set to 1 if a calculation results in a carry or borrow operation from bit 7, otherwise cleared to 0. This is also the shift-out value in a shift instruction.

The following general-purpose registers are provided:

General-purpose registers: 8-bit length, data storage registers

The general-purpose registers are 8 bits in length and located in the register banks in the memory. One bank contains eight registers and the MB89210 series allow a total of 16 banks to be used at maximum.

The bank currently in use is indicated by the register bank pointer (RP).



■ I/O MAP

Address	Register name	Register description	Read/write	Initial value				
0000н	PDR0	Port 0 data register	R/W	XXXXXXXX				
0001н	DDR0	Port 0 direction register	R/W	00000000				
0002н to 0006н	Access prohibited							
0007н	SYCC	System clock control register	R/W	1 1 1 1 0 0				
0008н	STBC	Standby control register	R/W	00010				
0009н	WDTC	Watchdog timer control register	W	0 XXXX				
000AH	TBTC	Time base timer control register	R/W	00000				
000BH		Access prohibited		1				
000Сн	PDR1	Port 1 data register	R/W	XXXXXXXX				
000Dн	DDR1	Port 1 direction register	R/W	00000000				
000Eн	RSFR	Reset flag register	R	XXXX				
000Fн	PDR2	Port 2 data register	R/W	XXXX				
0010н	DDR2	Port 2 direction register	R/W	0000				
0011 н		Access prohibited	1	1				
0012н	PDR3	Port 3 data register	R/W	XX				
0013н	DDR3	Port 3 direction register	R/W	0				
0014н	RCR21	12-bit PPG control register 1	R/W	00000000				
0015 н	RCR22	12-bit PPG control register 2	R/W	000000				
0016 н	RCR23	12-bit PPG control register 3	R/W	0-000000				
0017 н	RCR24	12-bit PPG control register 4	R/W	000000				
0018 н		Access prohibited						
0019 н	TCCR0	Capture control register 0	R/W	00000000				
001Ан	TCR10	Timer 1 control register 0	R/W	000-0000				
001Bн	TCR00	Timer 0 control register 0	R/W	00000000				
001Cн	TDR10	Timer 1 Data 0	R/W	XXXXXXXX				
001Dн	TDR00	Timer 0 Data 0	R/W	XXXXXXXX				
001Е н	TCPH0	Capture data register H 0	R	XXXXXXXX				
001Fн	TCPL0	Capture data register L 0	R	XXXXXXXX				
0020н	TCR20	Timer output control 0	R/W	00				
0021н		Access prohibited	I	1				
0022н	CNTR	PWM control register	R/W	0-000000				
0023н	COMR	PWM Compare register	W	XXXXXXXX				
0024н	EIC1	External interrupt control register 1 (edge)	R/W	00000000				
0025н	EIC2	External interrupt control register 2 (edge)	R/W	00000000				

(Continued)

Address	Register name	Register description	Read/write	Initial value
0026н				
0027н		Access prohibited		
0028н	SCR	Serial control register	R/W	00000000
0029н	USMR	LIN-UART serial mode register	R/W	00000000
002Ан	SSR	Serial status register	R/W	00001000
0000	RDR	Recieving data register	R	00000000
002Bн	TDR	Sending data register	W	11111111
002Сн	ESCR	Extended status control register	R/W	00000X00
002Dн	ECCR	Extended communication control register	R/W	00000-11
002Eн	BGRH	Baud rate generator register H	R/W	-0000000
002Fн	BGRL	Baud rate generator register L	R/W	00000000
0030н	ADC1	A/D control register 1	R/W	00000000
0031н	ADC2	A/D control register 2	R/W	00000001
0032н	ADDH	A/D data register H	R/W	00000XX
0033н	ADDL	A/D data register L	R/W	XXXXXXXX
0034н	ADEN	A/D enable register	R/W	00000000
0035н to 0038н		Access prohibited	- -	
0039н	SMR	Serial mode register	R/W	00000000
003Ан	SDR	Serial Data register	R/W	XXXXXXXX
003Bн to 0040н		Access prohibited		
0041н	TCCR1	Capture control register 1	R/W	00000000
0042н	TCR11	Timer 1 control register 1	R/W	000-0000
0043н	TCR01	Timer 0 control register 1	R/W	00000000
0044н	TDR11	Timer 1 Data register 1	R/W	XXXXXXXX
0045н	TDR01	Timer 0 Data register 1	R/W	XXXXXXXX
0046н	TCPH1	Capture status register H1	R	XXXXXXXX
0047н	TCPL1	Capture status register L1	R	XXXXXXXX
0048н	TCR21	Timer output control register 1	R/W	00
0049н	TCSL	Capture input select register	R/W	0
004Ан to 005Fн		Access prohibited		
0060н	XCRS*	External/CR(built-in)oscillation clock control register	R/W	00-00010
0061н to 006Fн		Access prohibited		

(Continued)

(Continued)								
Address	Register name	Register description	Read/write	Initial value				
0070н	PUL0	Port 0 pull-up setting register	R/W	00000000				
0071н	PUL1	Port 1 pull-up setting register	R/W	00000000				
0072н	PUL2	Port 2 pull-up setting register	R/W	0000				
0073н	PUL3	Port 3 pull-up setting register	R/W	0				
0074н to 0079н	Access prohibited							
007Ан	FMCS	Flash memory control status register	R/W	$0\ 0\ 0\ 0\ 0\ 0\ -0$				
007Bн	ILR1	Interrupt level setting register 1	W	11111111				
007Сн	ILR2	Interrupt level setting register 2	W	11111111				
007Dн	ILR3	Interrupt level setting register 3	W	11111111				
007Eн	ILR4	Interrupt level setting register 3	W	11111111				
007Fн	07F _H Access prohibited							

*: Only for MB89215, MB89F217, MB89P215

Description of write/read symbols :

R/W : Read/write enabled

- R : Read only
- W : Write only

Description of initial values

- 0 : This bit initialized to "0".
- 1 : This bit initialized to "1".
- X : The initial value of this bit is undefined.
- : This bit is not defined.
- Note : If a bit manipulation instruction accesses the serial mode register (SMR), a write-only register, or a register containing a write-only bit, the bit focused on by the instruction is set to a prescribed value but a malfunction occurs when the other bits contains a write-only bit. Do not use bit manipulation instructions to access such registers.

ELECTRICAL CHARACTERISTICS

1. Absolute Maximum Ratings

Parameter	Symbol	Rat	ing	Unit	Remarks
Parameter	Symbol	Min	Max	Unit	Remarks
Power supply voltage	Vcc	Vss – 0.3	Vss + 6.0	V	
Input voltage	Vı	Vss - 0.3	Vcc + 0.3	V	*2
Output voltage	Vo	Vss - 0.3	Vss + 6.0	V	
Maximum clamp current		- 0.4	+ 0.4	mA	*1
Maximum clamp total current			10	mA	*1
"L" level output current	lol		10	mA	
"L" level average current	Iolav		4	mA	Average value (operating current × operating duty)
"L" level total output current	ΣΙοι		50	mA	
"H" level output current	Іон		- 10	mA	
"H" level average current	Іонач	_	- 4	mA	Average value (operating current × operating duty)
"H" level total output current	ΣІон		- 50	mA	
Power consumption	Pd		200	mW	MB89215, MB89P215
Power consumption	Fu		300	mW	MB89F217
Storage temperature	Tstg	- 55	+ 150	°C	

*1 : • Applicable to pins : P00 to P07, P10 to P17, P20 to P23, P30 to P31

• Use within recommended operating conditions.

- Use at DC voltage (current) .
- The +B signal should always be applied with a limiting resistance placed between the +B signal and the microcontroller.
- The value of the limiting resistance should be set so that when the +B signal is applied the input current to the microcontroller pin does not exceed rated values, either instantaneously or for prolonged periods.
- Note that when the microcontroller drive current is low, such as in the power saving modes, the +B input potential may pass through the protective diode and increase the potential at the Vcc pin, and this may affect other devices.
- Note that if a +B signal is input when the microcontroller current is off (not fixed at 0 V), the power supply is provided from the pins, so that incomplete operation may result.
- Note that if the +B input is applied during power-on, the power supply is provided from the pins and the resulting supply voltage may not be sufficient to operate the power-on reset.
- Care must be taken not to leave the +B input pin open.
- Note that analog system input/output pins other than the A/D input pins (LCD drive pins, comparator input pins, etc.) cannot accept +B signal input.

(Continued)

(Continued)

Sample recommended circuits :



- *2 : If the maximum current to/from an input is limited by some means with external components, the ICLAMP rating supersedes the VI rating.
- WARNING: Semiconductor devices can be permanently damaged by application of stress (voltage, current, temperature, etc.) in excess of absolute maximum ratings. Do not exceed these ratings.

Parameter	Symbol	Va	lue	Unit	Remarks
Faiametei	Symbol	Min	Max	Unit	Reliai NS
Power supply voltage	Vcc	3.5	5.5	V	Normal Operation Assurance Range
		3.0	5.5	V	RAM status in stop mode
	Vін	0.7 Vcc	Vcc + 0.3	V	P31,UI
Input "H" voltage	Vins	0.8 Vcc	Vcc + 0.3	V	MODA, MOD0, MOD1, RST, P00 to P07, P10 to P17, P20 to P23, P30, INT0 to INT2, EC0, EC1, SCK, SI, UCK
	VIL	Vss - 0.3	0.3 Vcc	V	P31,UI
Input "L" voltage	Vils	Vss – 0.3	0.2 Vcc	V	MODA, MOD0, MOD1, RST, P00 to P07, P10 to P17, P20 to P23, P30, INT0 to INT2, EC0, EC1, SCK, SI, UCK
Operating temperature	Та	- 40	+ 105	°C	

2. Recommended Operating Conditions



WARNING: The recommended operating conditions are required in order to ensure the normal operation of the semiconductor device. All of the device's electrical characteristics are warranted when the device is operated within these ranges.

Always use semiconductor devices within their recommended operating condition ranges. Operation outside these ranges may adversely affect reliability and could result in device failure.

No warranty is made with respect to uses, operating conditions, or combinations not represented on the data sheet. Users considering application outside the listed conditions are advised to contact their FUJITSU representatives beforehand.

3. DC Characteristics

(Vcc = 5.0 V \pm 10%, Vss = 0.0 V, FcH = 10 MHz (external clock), Ta = -40 °C to +105 °C)

Demonster			D'a a care	Constitue		Value		11	Demender
Parameter	Symbol		Pin name	Condition	Min	Тур	Max	Unit	Remarks
	Vін	P31,	UI		0.7 Vcc		Vcc + 0.3	V	
"H" level input voltage _{Vнs}		MODA, MOD0, MOD1, RST, P00 to P07, P10 to P17,P20 to P23, P30, INT0 to INT2, EC0, EC1, SCK, SI, UCK			0.8 Vcc		Vcc + 0.3	V	
	VIL	P31,	UI		Vss - 0.3	_	0.3 Vcc	V	
"L" level input voltage	Vils	RST P10 P30,	DA, MOD0, MOD1, , P00 to P07, to P17,P20 to P23, INT0 to INT2, EC0, , SCK, SI, UCK		Vss-0.3		0.2 Vcc	V	
"H" level output voltage	Vон		to P07, P10 to P17, to P23, P30	Vcc = 4.5 V, Іон = -4.0 mA	Vcc-0.5			V	
"L" level output voltage	Vol			Vcc = 4.5 V, Io∟ = 4.0 mA	—		0.4	V	
Input leak current	Lı	P20	to P07, P10 to P17, to P23, P30, P31, DA, MOD0, MOD1	0.45 V < Vı < Vcc		_	± 5	μA	Without pull-up resistance specified
Pullup resistance	Rpull		to P07,P10 to P17, to P23, P30, RST	$V_I = 0.0 V$	25	50	100	kΩ	
					—	8	12	mA	MB89215
			At normal	When A/D convereter stops		6	10	mA	MB89F217
	lcc		operating		—	6	9	mA	MB89P215
	ICC		(External clock,			11	15	mA	MB89215
			Max gear speed)	When A/D convereter starts		8	13	mA	MB89F217
Power supply		Vcc				8	12	mA	MB89P215
current			at sleep mode	When A/D		4	6	mA	MB89215
	Iccs		(External clock, Max gear speed)	convereter stops		3	5	mA	MB89F217, MB89P215
		1	At stop mode	When A/D		—	1	μΑ	MB89215
	Іссн		Ta = +25 °C (External clock)	convereter stops			10	μA	MB89F217, MB89P215
Input capacitance	CIN	Othe	r than Vcc and Vss	_		5	15	pF	MB89F217, MB89P215

4. AC Characteristics

(1) Reset Timing

(Vss = 0.0 V, Ta = -40 °C to +105 °C)

Parameter	Symbol	Condition	Va	lue	Unit	Remarks			
Faranteler	Symbol	Condition	Min	Max	Unit	Kennarka			
RST "L" level pulse width	tzlzh		48 thcyL*		ns				
* : they: : Oscillation clock one cycle time									
RST		- 0.2 Vcc).2 Vcc		-			

(2) Power-on reset

(Vss = 0.0 V, Ta = -40 °C to +105 °C)

Parameter	Symbol	Condition	Va	lue	Unit	Remarks	
Farameter	Symbol	Condition	Min	Мах	Onit	iverilar N3	
Power on time	tR	—	—	50	ms		
Power shutoff time	toff		1		ms	For repeated operation	



Note : The supply voltage must be set to minimum value required for operation within the prescribed default oscillation setting time.

(3) Clock Timing

(Vss = 0.0 V, Ta = -40 °C to +105 °C)

Parameter	Symbol	Condition	Va	lue	Unit	Remarks	
Parameter	Symbol	Condition	Min	Max	Unit	Relliarks	
Clock frequency	Г сн-1		1	12.5	MHz		
Clock cycle time	t xcyL	Crystal or	80	1000	ns		
Input clock pulse width	twн tw∟	Crystal or ceramic oscillation	20		ns		
Input clock rise, fall time	tcr tcf			10	ns		
Oscillation frequency	Fсн-2	CR(built-in) oscillator	8.5	11.5	MHz		



(4) Instruction Cycle

(Vss = 0.0 V, Ta = -40 °C to +105 °C)

Parameter	Symbol	Value	Unit	Remarks
Instruction cycle (instruction execution time)	t INST	4/Есн, 8/Есн, 16/Есн, 64/Есн		When operating at $F_{CH} = 10 \text{ MHz}$ tinst = 0.4 μ s (4/F _{CH})

FCH: Oscillation frequency (Operating clock frequency after switching between external and CR (internal) oscillator clocks)

(5) Recommended Resonator Manufactures

• Sample application of ceramic resonator



Resonator manufacture	Resonator	Frequency (MHz)	C 1	C ₂	R
Murata Mfg. Co., Ltd.	CSTLS4M00G56-B0	4.00 A00G56-B0		built-in	680 Ω
	CSTCR4M00G55-R0	4.00	built-in	built-in	680 Ω
	CSTLS8M00G53-B0	8.00	built-in	built-in	—
	CSTCC8M00G53-R0	8.00	built-in	built-in	
	CSTLS10M0G53-B0	10.00	built-in	built-in	
	CSTCC10M00G53-R0	10.00	built-in	built-in	

Inquiry : • Murata Electronics North America Inc : TEL +1-404-436-1300

Murata Europe Management GmbH : TEL +49-911-66870
 Murata Electronics Singapore (p/e) : TEL +65-758-4233

(6) Peripheral Input Timing

 $(V_{CC} = 5.0 \text{ V} \pm 10\%, \text{ Vss} = 0.0 \text{ V}, \text{ Ta} = -40 \text{ }^{\circ}\text{C} \text{ to} +105 \text{ }^{\circ}\text{C})$

Symbol	Din namo	Va	lue	Unit	Remarks
	Fininame	Min	Max		
tı∟ıн	INT0 to INT2,	2 tinst*		μs	
tıнı∟	EC0, EC1	2 tinst*	_	μs	
-	tilih	ti⊔i⊢ INT0 to INT2,	Symbol Pin name tillit INT0 to INT2, 2 tillit*	Min Max tillit INT0 to INT2, 2 tillist* —	Symbol Pin name Min Max Unit tiμH INT0 to INT2, 2 tinst* — μs

*: For tINST see " (4) Instruction Cycle".



(7) Serial I/O Timing

$(Vcc = 5.0 \text{ V} \pm 10\%, \text{ Vss} = 0.0 \text{ V}, \text{ Ta} = -40 \text{ °C to } +105 \text{ °C})$								
Parameter	Symbol	Pin name	Condition	Value		Unit	Remarks	
			Condition	Min	Max	Unit	Neillai KS	
Serial clock cycle time	tscyc	SCK	Internal clock operation	2 tinst*		μs		
$SCK \downarrow \rightarrow SO$ time	tslov	SCK, SO		- 200	200	ns		
Valid SI $ ightarrow$ SCK \uparrow	t i∨sн	SCK, SI		0.5 tinst*		μs		
$SCK \uparrow \to Valid \ SI \ hold \ time$	tsнix	SCK, SI		0.5 tinst*		μs		
Serial clock "H" pulse width	t shsl	SCK	External clock operation	tinst*		μs		
Serial clock "L" pulse width	t _{SLSH}	SCK		tinst*		μs		
$SCK \downarrow \rightarrow SO$ time	tslov	SCK, SO		0	200	ns		
Valid SI \rightarrow SCK \uparrow	t i∨sн	SCK, SI		0.5 tinst*		μs		
$SCK \uparrow \to Valid SI hold time$	tsнix	SCK, SI		0.5 tinst*		μs		

*: For tINST see "(4) Instruction Cycle".



(8) LIN-UART timing

$(Vcc = 5.0 V \pm 10\%, Vss = 0.0 V, Ta = -40 °C t0 + 105 °C$								
Parameter	Symbol	Pin name	Condition	Value		Unit	Remarks	
			Condition	Min	Мах	Unit	itemai ka	
Serial clock cycle time	tscyc	UCK		2 tinst*		μs		
$UCK \downarrow \rightarrow UO$ time	tslov	UCK, UO		- 200	200	ns		
Valid UI \rightarrow UCK \uparrow	t i∨sн	UCK, UI	Internal clock operation	0.5 tinst*	_	μs		
UCK $\uparrow \rightarrow$ Valid UI hold time	tsнix	UCK, UI		0		μs		
$UCK \downarrow \rightarrow UO$ time	t slov	UCK, UO		- 200	200	ns	SCDE = 1	
UCK (delay) $\downarrow \rightarrow$ UO time	tsclк	UCK (delay), UO		- 0.5 tinst*		μs	SCDE = 1	
$UCK\downarrow ightarrowUCK$ (delay) \downarrow	tsdel	UCK, UCK (de- lay)		0.5 tinst*		μs	SCDE = 1	
Serial clock "H" pulse width	t shsl	UCK	External clock operation	1.5 tinst*		μs		
Serial clock "L" pulse width	tslsh	UCK		1.5 tinst*	_	μs		
$UCK \downarrow \rightarrow UO$ time	t slov	UCK, UO		tinst*		μs		
Valid UI \rightarrow UCK \uparrow	tı∨sн	UCK, UI		0		μs		
$UCK \uparrow \to Valid UI hold time$	tsнix	UCK, UI		0.5 tinst*		μs		

*: For t_{INST} see " (4) Instruction Cycle".

(Vcc = 5.0 V ± 10%, Vss = 0.0 V, Ta = -40 °C to +105 °C)


5. A/D Converter

(1) A/D converter electrical characteristics

(Vcc = 5.0 V + 10%)	, Vss = 0.0 V, Ta = −40	0 °C to +105 °C)
---------------------	-------------------------	------------------

Parameter	Symbol	Value				Remarks
Falameter		Min	Тур	Max	Unit	Nellia KS
Resolution		—	—	10	bit	
Total error		- 5.0	—	+ 5.0	LSB	
Linearity error	1 —	- 3.0		+ 3.0	LSB	
Differential linear error		- 2.5		+ 2.5	LSB	
Zero transition voltage	Vот	Vss – 3.5 LSB	Vss + 0.5 LSB	Vss + 4.5 LSB	V	
Full-scale transition voltage	Vfst	Vcc - 6.5 LSB	Vcc – 1.5 LSB	Vcc + 2.0 LSB	V	
A/D mode conversion time	—	—		38 tinst*	μs	
Analog input current	IAIN	—	—	10	μΑ	
Analog input voltage range		0	—	Vcc	V	

* : For t_{INST} see " (4) Instruction Cycle" in "4. AC Characteristics".

(2) Definition of A/D Converter Terms

Resolution

The level of analog variation that can be distinguished by the A/D converter.

When the number of bits is 10, analog voltage can be divided into $2^{10} = 1024$.

- Linear error (Unit : LSB) The deviation between the value along a straight line connecting the zero transition point("00 0000 0000" ←→"00 0000 0001") of a device and the full-scale transition point ("11 1111 1111" ←→"11 1111 1110"), compared with the actual conversion values obtained.
- Differential linear error (Unit : LSB) Deviation of input voltage, which is required for changing output code by 1 LSB, from an ideal value.

• Total error (Unit : LSB) The difference between theoretical conversion value and actual conversion value.





(3) Precautionary Information of A/D conversion

Input Impedance of Analog Input Pins

The A/D converter has a sample & hold circuit as shown below, which uses a sample-and-hold capacitor to obtain the voltage at the analog input pin for 16 instruction cycles following the start of A/D conversion. For this reason if the external circuits providing the analog input signal have high output impedance, the analog input voltage may not stabilize within the analog input sampling time. It is therefore recommended that the output impedance of external circuits be reduced to 4 k Ω or less.

Note that if the impedance cannot be kept low, it is recommended to connect an external capacitor of about 0.1 μ F for the analog input pin.



About errors

The smaller the absolute value $|V_{CC} - V_{SS}|$ is, the greater the relative error becomes.

6. Electrical Characteristics of Flash Memory

• Programming and erasing characteristics

Parameter		Symbol	Pin	Condition	Value		Unit	Remarks		
	Faranteter		Symbol	Name	Condition	Min	Тур	Мах	Unit	itema ka
Power supply	Power supply current *1		IFWE	Vcc	Vcc = 5.0 V	—	_	40	mA	
Sector erase	Per 1 sector, constant value	Successful completion time	_		_		1	15	S	
time independent with sector capacitance	Unsuccessful completion time	_	_	_		_	*2			
Programming time	Per 1 byte	Successful completion time					8	3600	μs	
		Unsuccessful completion time					650	3600	μs	

*1 : Embedded Algorithm executing.

*2 : If a fault occurs during sector erasing, detection via DQ_5 may not be available ($DQ_5 = 1$ may not occur). Accordingly, a fault must be assumed after 15 s, even if DQ_5 does not go to "1".

■ EXAMPLE CHARACTERISTICS

(1) Power Supply Current



(Continued)



(2) Frequency Characteristics





■ MASK OPTIONS

No	Part number	MB89215	MB89F217	MB89P215	MB89PV210	
NO	Specifying procedure	Setting disallowed				
1	Initial value* selection of internal clock oscillation stabilization wait time (at $F_{CH} = 10 \text{ MHz}$) • 01 : 2 ¹⁴ /F _{CH} (Approx. 1.63 ms) • 10 : 2 ¹⁷ /F _{CH} (Approx. 13.1 ms) • 11 : 2 ¹⁸ /F _{CH} (Approx. 26.2 ms)		2 ¹⁸ /Fсн (Аррі	rox. 26.2 ms)		
2	Power-on reset • Power-on reset ON • Power-on reset OFF	Yes				
3	Reset pin output Reset output ON Reset output OFF 		Y	es		

FCH : Base oscillator

*: Initial value to which the oscillation setting time bit (sync: WT1, WT0) in the system clock control register is set.

■ ORDERING INFORMATION

Part number	Package	Remarks
MB89215PFV MB89P215PFV	30-pin Plastic SSOP (FPT-30P-M02)	
MB89215PFM MB89F217PFM	48-pin Plastic QFP (FPT-48P-M13)	
MB89PV210CF	48-pin Ceramic MQFP (MQP-48C-P02)	

■ PACKAGE DIMENSIONS







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